

UNISONIC TECHNOLOGIES CO., LTD

4N70K Power MOSFET

4.4A, 700V N-CHANNEL POWER MOSFET

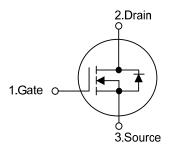
■ DESCRIPTION

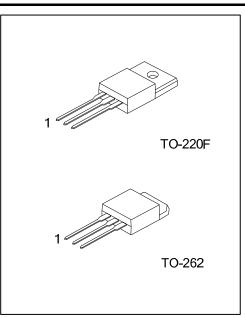
The UTC **4N70K** is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and high rugged avalanche. This high speed switching power MOSFET is usually used in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.

■ FEATURES

- * $R_{DS(ON)}$ < 2.8 Ω @ V_{GS} = 10 V
- * Fast Switching Capability
- * Avalanche Energy Specified
- * Improved dv/dt Capability, High Ruggedness

■ SYMBOL

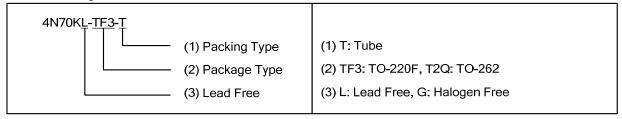




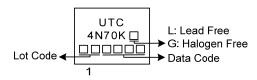
■ ORDERING INFORMATION

| Ordering Number | | Doolsons | Pin Assignment | | | Deeking | |
|-----------------|--------------|----------|----------------|---|---|---------|--|
| Lead Free | Halogen Free | Package | 1 | 2 | 3 | Packing | |
| 4N70KL-TF3-T | 4N70KG-TF3-T | TO-220F | G | D | S | Tube | |
| 4N70KL-T2Q-T | 4N70KG-T2Q-T | TO-262 | G | D | S | Tube | |

Note: Pin Assignment: G: Gate D: Drain S: Source



■ MARKING



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■ **ABSOLUTE MAXIMUM RATINGS** (T_A = 25°C, unless otherwise specified)

| PARAMETER | | SYMBOL | RATINGS | UNIT |
|------------------------------------|------------------------|------------------|------------|------|
| Drain-Source Voltage | | V_{DSS} | 700 | V |
| Gate-Source Voltage | | V_{GSS} | ±30 | V |
| Avalanche Current (Note 2) | | I _{AR} | 4.4 | Α |
| Drain Current | Continuous | I _D | 4.4 | Α |
| | Pulsed (Note 2) | I _{DM} | 17.6 | Α |
| Avalanche Energy | Single Pulsed (Note 3) | E _{AS} | 120 | mJ |
| | Repetitive (Note 2) | E _{AR} | 10.6 | mJ |
| Peak Diode Recovery dv/dt (Note 4) | | dv/dt | 4.5 | V/ns |
| Power Dissipation | TO-220F | Б | 36 | 10/ |
| | TO-262 | P _D | 106 | W |
| Junction Temperature | | TJ | +150 | °C |
| Operating Temperature | | T _{OPR} | -55 ~ +150 | °C |
| Storage Temperature | | T _{STG} | -55 ~ +150 | °C |

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating: Pulse width limited by maximum junction temperature
- 3. L = 15mH, I_{AS} = 4 A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25°C
- 4. $I_{SD} \le 4.4A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

■ THERMAL DATA

| PARAMETER | | SYMBOL | RATINGS | UNIT |
|---------------------|---------|-----------------|---------|-------|
| Junction to Ambient | | θ_{JA} | 62.5 | °C/W |
| Junction to Case | TO-220F | θ _{JC} | 3.47 | %0.0A |
| | TO-262 | | 1.18 | °C/W |

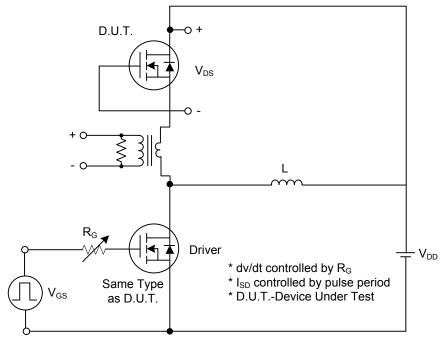
■ **ELECTRICAL CHARACTERISTICS** (T_A =25°C, unless otherwise specified)

| PARAMETER | | SYMBOL | TEST CONDITIONS | | TYP | MAX | UNIT | |
|---|------------------|---|---|-----|-----|------|------------|--|
| OFF CHARACTERISTICS | | | | | • | • | | |
| Drain-Source Breakdown Voltage | | BV _{DSS} | $V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$ | 700 | | | V | |
| Drain-Source Leakage Current | | I _{DSS} | V _{DS} = 700 V, V _{GS} = 0 V | | | 10 | μA | |
| Gate-Source Leakage Current | Forward | locc l | $V_{GS} = 30 \text{ V}, V_{DS} = 0 \text{ V}$ | | | 100 | π Λ | |
| | Reverse | | $V_{GS} = -30 \text{ V}, V_{DS} = 0 \text{ V}$ | | | -100 | nA | |
| Breakdown Voltage Temperature Coefficient | | $\triangle BV_{DSS} \! / \triangle T_J$ | I_D = 250µA, Referenced to 25°C | | 0.6 | | V/°C | |
| ON CHARACTERISTICS | | | | | | | | |
| Gate Threshold Voltage | | $V_{GS(TH)}$ | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | 2.0 | | 4.0 | V | |
| Static Drain-Source On-State Resistance | | R _{DS(ON)} | V_{GS} = 10 V, I_{D} = 2.2 A | | 2.0 | 2.8 | Ω | |
| DYNAMIC CHARACTERISTICS | | | | | | | | |
| Input Capacitance | nput Capacitance | | V _{DS} = 25 V, V _{GS} = 0 V, f = 1MHz | | 660 | 760 | pF | |
| Output Capacitance | | C _{ISS} | | | 48 | 90 | pF | |
| Reverse Transfer Capacitance | | C_{RSS} | | | 5 | 11 | pF | |
| SWITCHING CHARACTERISTIC | S | | | | | | | |
| Turn-On Delay Time | | $t_{D(ON)}$ | $V_{DD} = 30V, I_D = 0.5A,$ $R_G = 25\Omega \text{ (Note 1, 2)}$ | | 74 | | ns | |
| Turn-On Rise Time | | t_R | | | 34 | | ns | |
| Turn-Off Delay Time | | $t_{D(OFF)}$ | | | 174 | | ns | |
| Turn-Off Fall Time | | t_{F} | | | 41 | | ns | |
| Total Gate Charge | | Q_G | V _{DS} = 50V, I _D = 1.3A, V _{GS} = 10 V (Note 1, 2) | | 19 | 25 | nC | |
| Gate-Source Charge | | Q_GS | | | 3.4 | | nC | |
| Gate-Drain Charge | | Q_GD | | | 7.1 | | nC | |
| SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS | | | | | | | | |
| Drain-Source Diode Forward Voltage | | V_{SD} | $V_{GS} = 0 \text{ V}, I_{S} = 4.4 \text{ A}$ | | | 1.4 | V | |
| Maximum Continuous Drain-Source Diode | | | | | | 4.4 | A | |
| Forward Current | | I _S | | | | 4.4 | ^ | |
| Maximum Pulsed Drain-Source Diode | | I _{SM} | | | | 17.6 | Α | |
| Forward Current | | | | | | 17.0 | | |

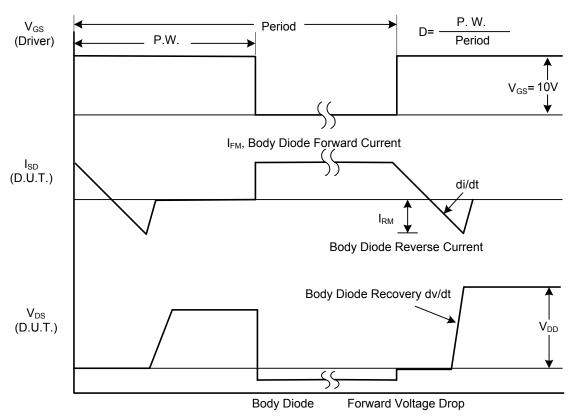
Notes: 1. Pulse Test: Pulse width ≤ 300µs, Duty cycle ≤ 2%

^{2.} Essentially independent of operating temperature

■ TEST CIRCUITS AND WAVEFORMS

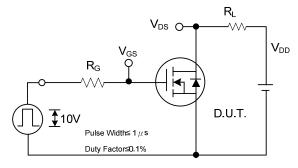


Peak Diode Recovery dv/dt Test Circuit

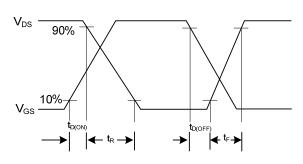


Peak Diode Recovery dv/dt Waveforms

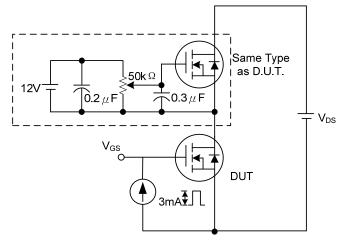
■ TEST CIRCUITS AND WAVEFORMS (Cont.)



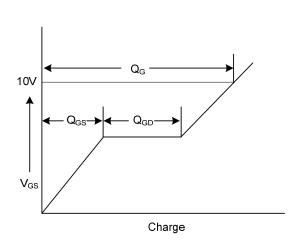
Switching Test Circuit



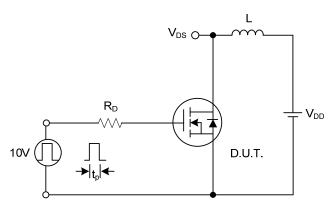
Switching Waveforms



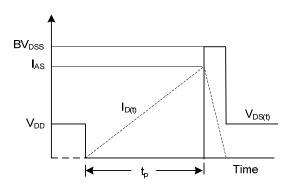
Gate Charge Test Circuit



Gate Charge Waveform

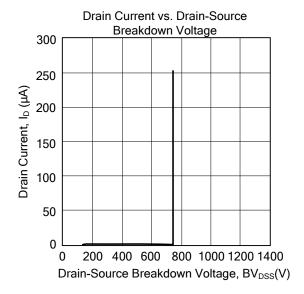


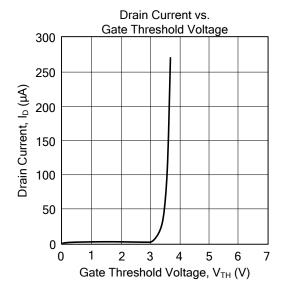
Unclamped Inductive Switching Test Circuit

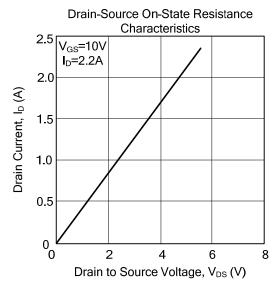


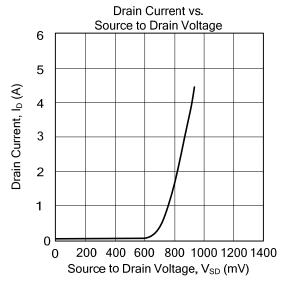
Unclamped Inductive Switching Waveforms

■ TYPICAL CHARACTERISTICS









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